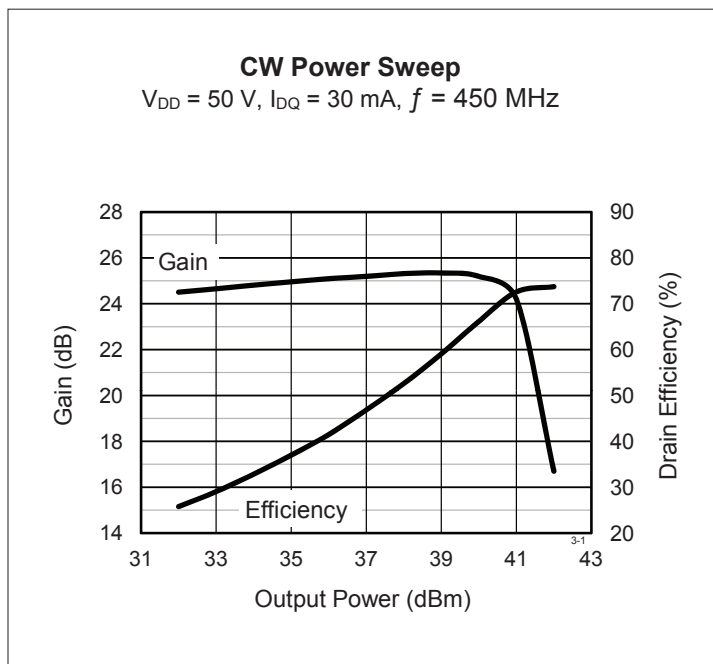
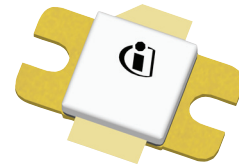


Thermally-Enhanced High Power RF LDMOS FET 12 W, 50 V, 390 – 450 MHz

Description

The PTVA030121EA is an LDMOS FET characterized for use in power amplifier applications in the 390 MHz to 450 MHz frequency band. Features include high gain and a thermally-enhanced package. Manufactured with Infineon's advanced LDMOS process, this device provides excellent thermal performance and superior reliability.

PTVA030121EA
Package H-36265-2



Features

- Unmatched input and output
- Integrated ESD protection
- Human Body Model Class 1C (per ANSI/ESDA/JEDEC JS-001)
- High gain, low thermal resistance
- Excellent ruggedness
- Capable of withstanding a 13:1 load mismatch at 50 V, 12 W, CW conditions
- Pb-free and RoHS compliant

RF Characteristics

CW Measurements

$V_{DD} = 50\text{ V}$, $I_{DQ} = 50\text{ mA}$, $P_{OUT} = 12\text{ W}$, $f = 450\text{ MHz}$

Characteristic	Symbol	Min	Typ	Max	Unit
Gain	Gps	23	25	—	dB
Drain Efficiency	η_D	66	69	—	%

All published data at $T_{CASE} = 25^\circ\text{C}$ unless otherwise indicated

ESD: Electrostatic discharge sensitive device—observe handling precautions!

DC Characteristics

Characteristic	Conditions	Symbol	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	$V_{GS} = 0\text{ V}$, $I_{DS} = 1\text{ mA}$	$V_{(BR)DSS}$	105	—	—	V
Drain Leakage Current	$V_{DS} = 50\text{ V}$, $V_{GS} = 0\text{ V}$	I_{DSS}	—	—	1.0	μA
	$V_{DS} = 105\text{ V}$, $V_{GS} = 0\text{ V}$	I_{DSS}	—	—	10.0	μA
On-State Resistance	$V_{GS} = 10\text{ V}$, $V_{DS} = 0.1\text{ V}$	$R_{DS(on)}$	—	2.8	—	Ω
Operating Gate Voltage	$V_{DS} = 50\text{ V}$, $I_{DQ} = 50\text{ mA}$	V_{GS}	—	3.6	—	V
Gate Leakage Current	$V_{GS} = 10\text{ V}$, $V_{DS} = 0\text{ V}$	I_{GSS}	—	—	1.0	μA

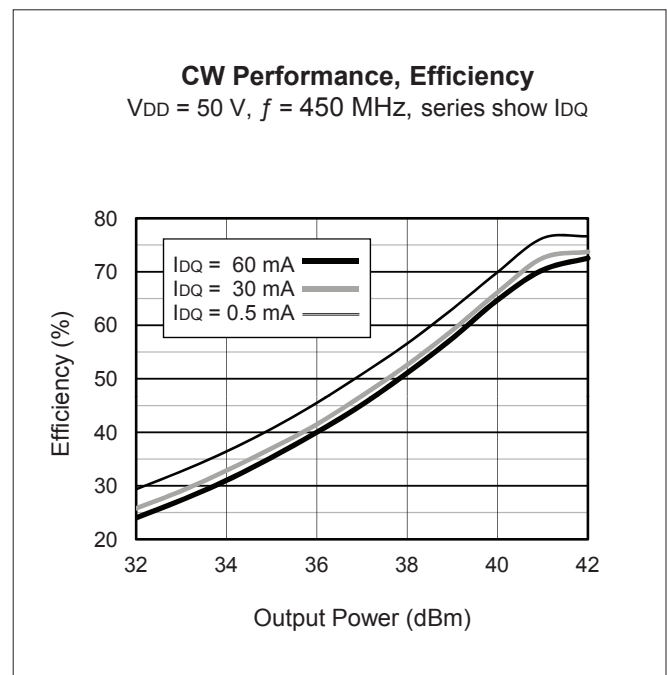
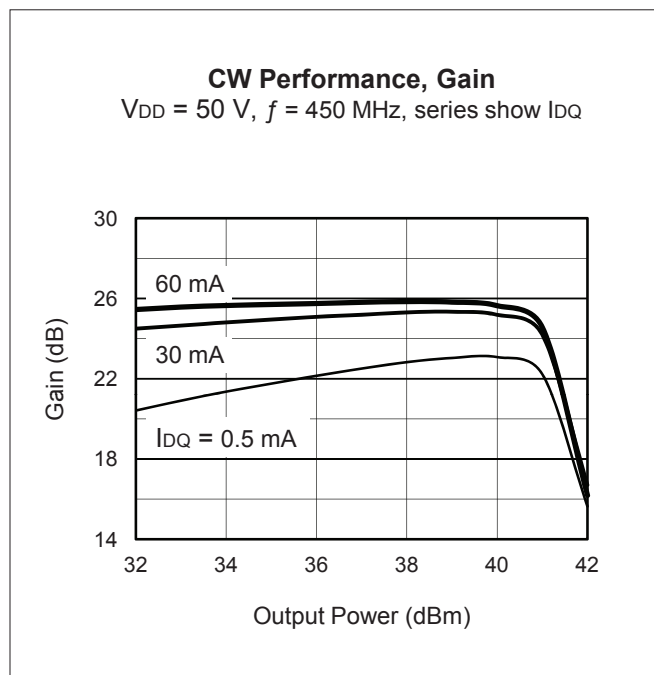
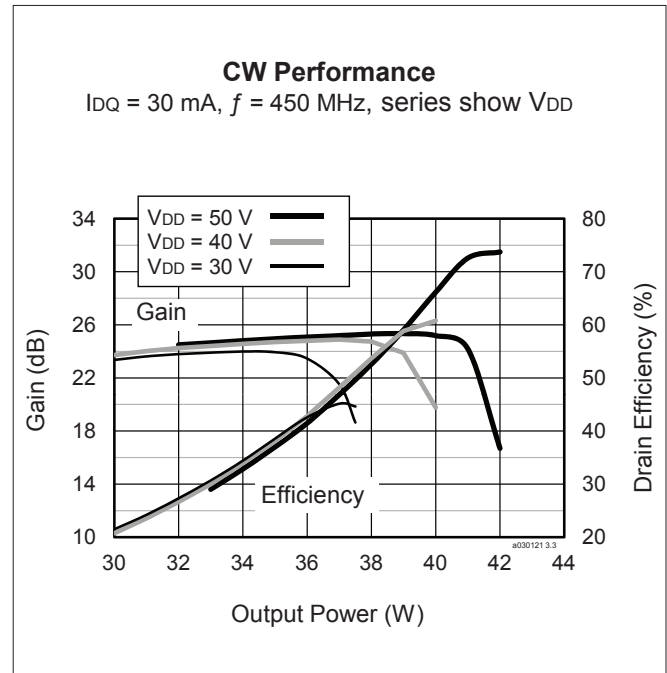
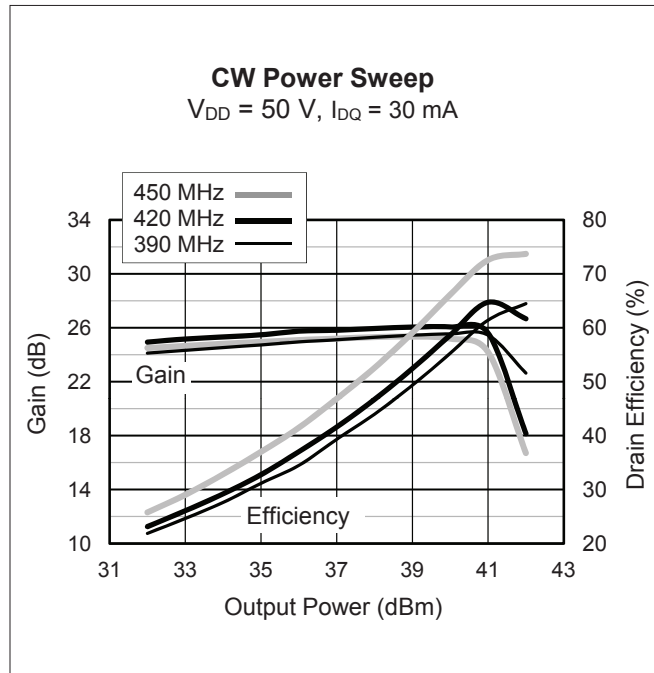
Maximum Ratings

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DSS}	105	V
Gate-Source Voltage	V_{GS}	−6 to +12	V
Junction Temperature	T_J	200	$^{\circ}\text{C}$
Storage Temperature Range	T_{STG}	−65 to +150	$^{\circ}\text{C}$
Thermal Resistance ($T_{CASE} 70^{\circ}\text{C}$, 12 W CW)	$R_{\theta JC}$	6.5	$^{\circ}\text{C/W}$

Ordering Information

Type and Version	Order Code	Package and Description	Shipping
PTVA030121EA V1 R0	PTVA030121EAV1R0XTMA1	H-36265-2, bolt-down	Tape & Reel, 50pcs
PTVA030121EA V1 R250	PTVA030121EAV1R250XTMA1	H-36265-2, bolt-down	Tape & Reel, 250pcs

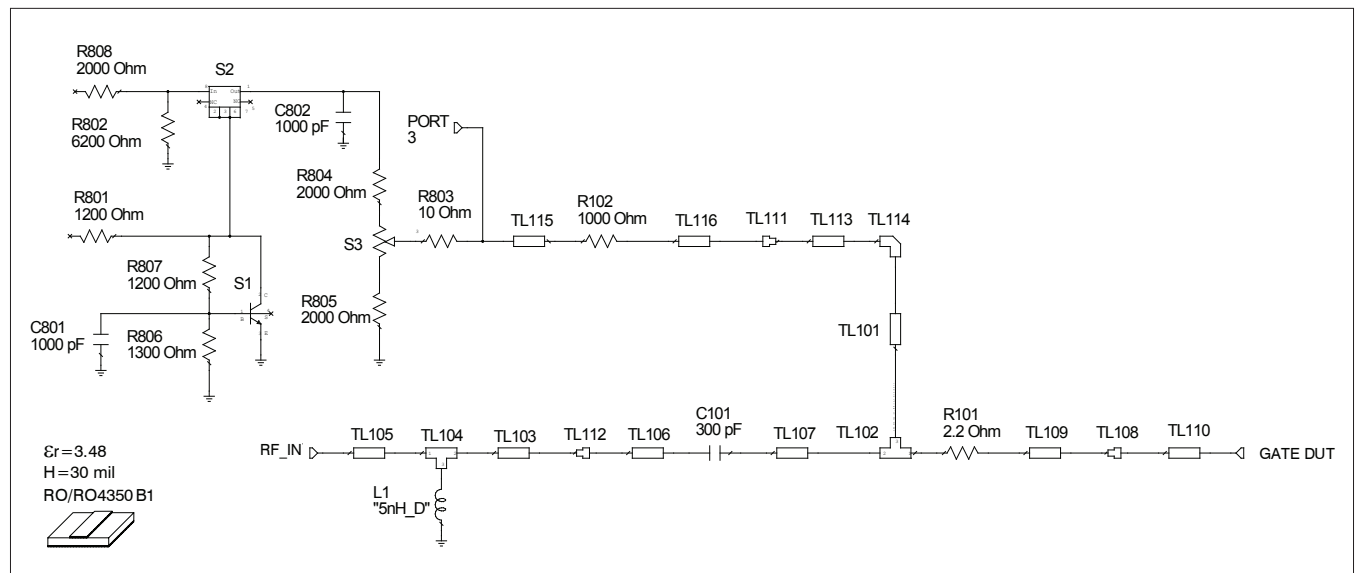
Typical Performance (data taken in a production test circuit)



Broadband Circuit Impedance

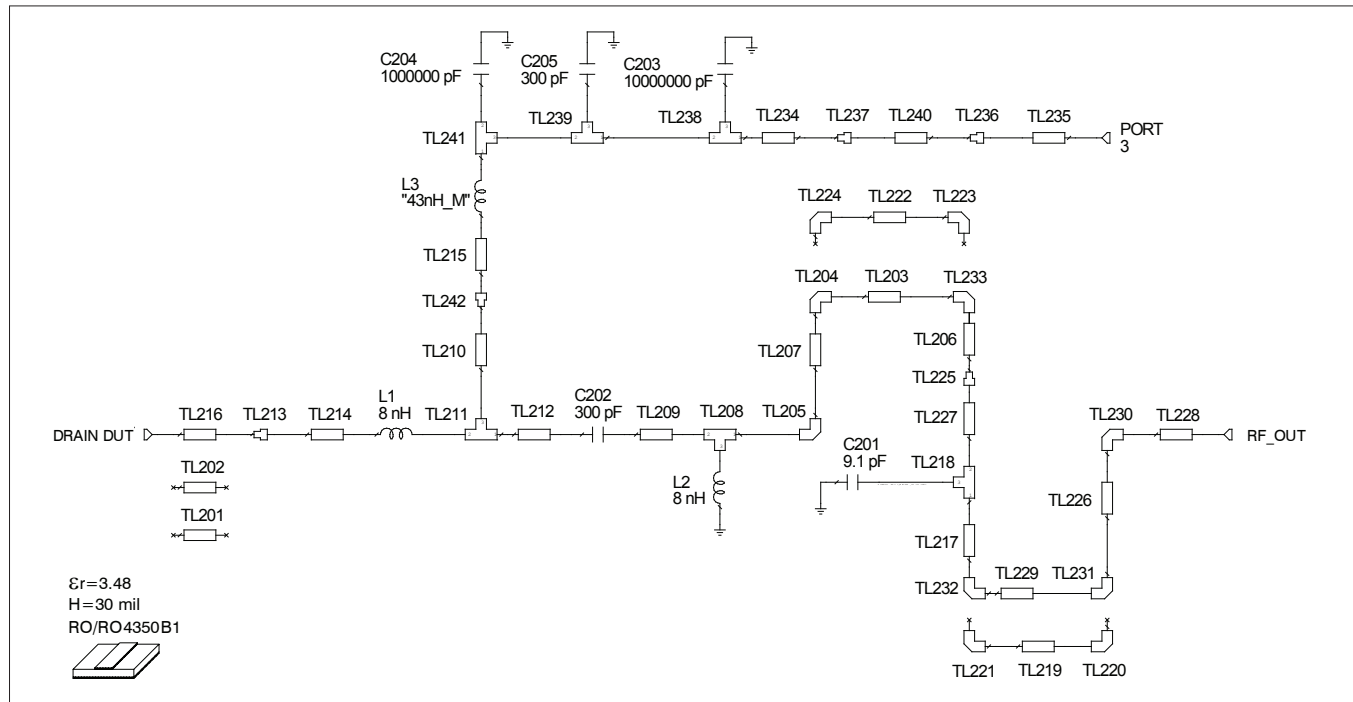
Frequency MHz	Z Source Ω		Z Load Ω	
	R	jX	R	jX
390	22.20	34.88	4.26	15.04
405	21.95	34.74	4.46	15.82
420	21.39	34.99	4.66	16.62
435	20.61	35.80	4.88	17.42
450	19.77	37.03	5.11	18.23

Reference Circuit



Reference circuit input schematic for $f = 450$ MHz

Reference Circuit (cont.)



Reference circuit output schematic for $f = 450 \text{ MHz}$

Reference Circuit Assembly

DUT PTFA030121EA

Test Fixture Part No. LTN/PTFA030121EA

PCB Rogers RO4350, 0.508 mm [0.020"] thick, 1 oz. copper, $\epsilon_r = 3.48$

Find Gerber files for this test fixture on the Infineon Web site at <http://www.infineon.com/rfpower>

Electrical Characteristics at 450 MHz

Transmission Line	Electrical Characteristics	Dimensions: mm	Dimensions: mils
Input			
TL101	0.009λ , 92.76Ω	$W = 0.51$, $L = 3.81$	$W = 20$, $L = 150$
TL102	0.001λ , 45.29Ω	$W1 = 2.03$, $W2 = 2.03$, $W3 = 0.51$	$W1 = 80$, $W2 = 80$, $W3 = 20$
TL103	0.001λ , 52.21Ω	$W = 1.63$, $L = 0.43$	$W = 64$, $L = 17$
TL105	0.025λ , 52.21Ω	$W = 1.63$, $L = 10.13$	$W = 64$, $L = 39$
TL106, TL109	0.003λ , 45.29Ω	$W = 2.03$, $L = 1.27$	$W = 80$, $L = 50$
TL107	0.002λ , 45.29Ω	$W = 2.03$, $L = 0.76$	$W = 80$, $L = 30$
TL110	0.013λ , 16.51Ω	$W = 7.62$, $L = 5.08$	$W = 300$, $L = 200$
TL113	0.002λ , 92.76Ω	$W = 0.51$, $L = 1.02$	$W = 20$, $L = 40$
TL115	0.013λ , 54.31Ω	$W = 1.52$, $L = 5.08$	$W = 60$, $L = 200$
TL116	0.003λ , 54.31Ω	$W = 1.52$, $L = 1.02$	$W = 60$, $L = 40$

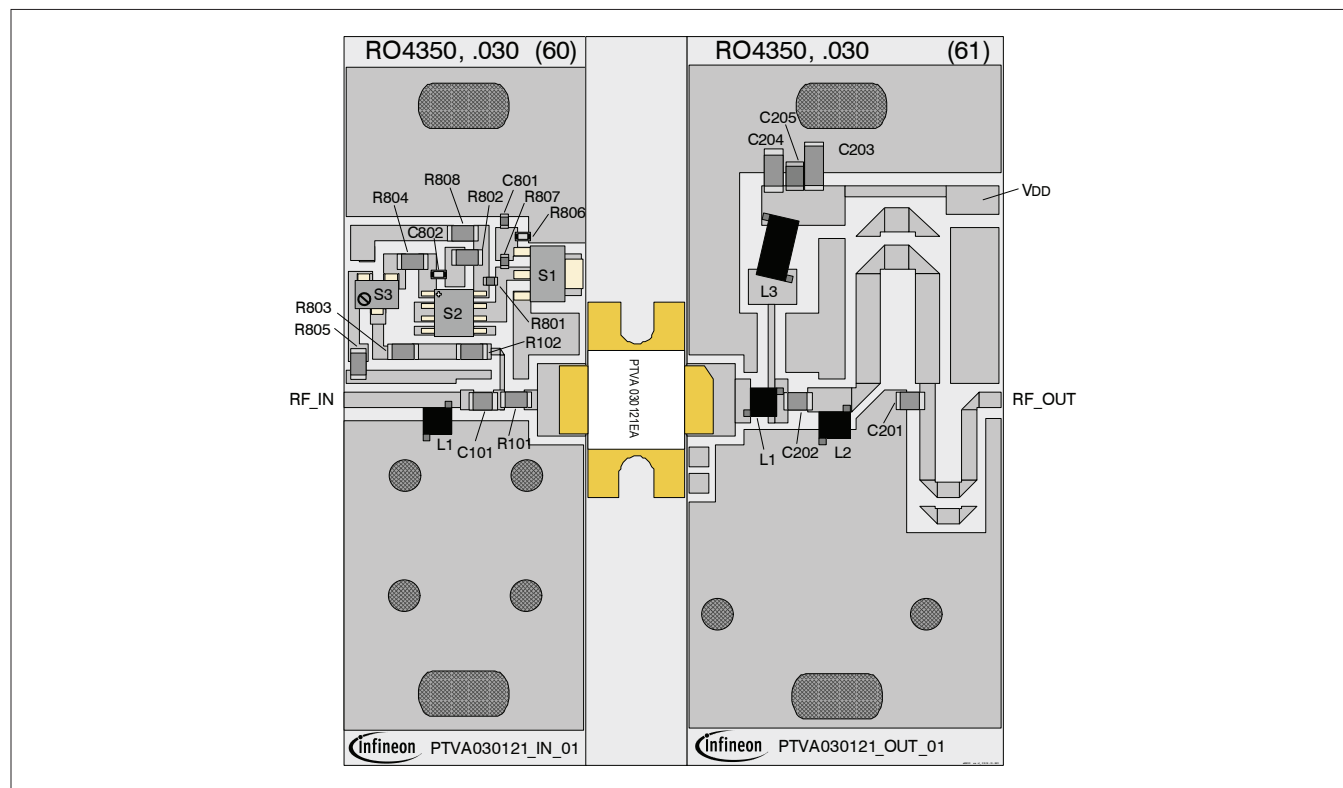
table continued next page

Reference Circuit (cont.)

Electrical Characteristics at 450 MHz

Transmission Line	Electrical Characteristics	Dimensions: mm	Dimensions: mils
Output			
TL201, TL202	0.005 λ , 45.29 Ω	W = 2.03, L = 2.04	W = 80, L = 81
TL203	0.006 λ , 38.92 Ω	W = 2.54, L = 2.54	W = 100, L = 100
TL206, TL207	0.029 λ , 38.92 Ω	W = 2.54, L = 11.43	W = 100, L = 450
TL209	0.009 λ , 38.92 Ω	W = 2.54, L = 3.56	W = 100, L = 140
TL210	0.018 λ , 78.46 Ω	W = 0.76, L = 7.62	W = 30, L = 300
TL211	0.002 λ , 25.11 Ω	W1 = 4.57, W2 = 4.57, W3 = 0.76	W1 = 180, W2 = 180, W3 = 30
TL212	0.003 λ , 25.11 Ω	W = 4.57, L = 1.27	W = 180, L = 50
TL214	0.004 λ , 25.11 Ω	W = 4.57, L = 1.52	W = 180, L = 60
TL215	0.010 λ , 23.09 Ω	W = 5.08, L = 3.81	W = 200, L = 150
TL216	0.013 λ , 16.51 Ω	W = 7.62, L = 5.08	W = 300, L = 200
TL217	0.018 λ , 52.21 Ω	W = 1.63, L = 7.29	W = 64, L = 287
TL219	0.006 λ , 52.21 Ω	W = 1.63, L = 2.41	W = 64, L = 95
TL222	0.006 λ , 38.92 Ω	W = 2.54, L = 2.54	W = 100, L = 100
TL226	0.018 λ , 52.21 Ω	W = 1.63, L = 7.34	W = 64, L = 289
TL227	0.002 λ , 52.21 Ω	W = 1.63, L = 0.84	W = 64, L = 33
TL228	0.006 λ , 52.21 Ω	W = 1.63, L = 2.30	W = 64, L = 91
TL229	0.006 λ , 52.21 Ω	W = 1.63, L = 2.41	W = 64, L = 95
TL234	0.005 λ , 27.14 Ω	W = 4.14, L = 2.12	W = 163, L = 84
TL235	0.014 λ , 34.38 Ω	W = 3.02, L = 5.51	W = 119, L = 2 17
TL240	0.026 λ , 61.53 Ω	W = 1.23, L = 10.63	W = 48, L = 419
TL241	0.010 λ , 38.92 Ω	W1 = 2.54, W2 2.54, W3 = 4.14	W1 = 100, W2 = 100, W3 = 163

Reference Circuit (cont.)



Reference circuit assembly diagram (not to scale)

Component ID	Description	Suggested Supplier	P/N
Input			
C101	Chip capacitor, 300 pF	ATC	ATC100B301JW200XB
C801, C802	Capacitor, 1000 pF	Panasonic Electronic Components	ECJ-1VB1H102K
L1	Inductor, 5 nH	Coilcraft	A02TGLB
R101	Resistor, 2.2 Ω	Panasonic Electronic Components	ERJ-8GEYJ2R2V
R102	Resistor, 1000 Ω	Panasonic Electronic Components	ERJ-8GEYJ102V
R801, R807	Resistor, 1200 Ω	Panasonic Electronic Components	ERJ-3GEYJ122V
R802	Resistor, 6200 Ω	Panasonic Electronic Components	ERJ-8GEYJ622V
R803	Resistor, 10 Ω	Panasonic Electronic Components	ERJ-8GEYJ100V
R804, R805, R808	Resistor, 2000 Ω	Panasonic Electronic Components	ERJ-8GEYJ202V
R806	Resistor, 1300 Ω	Panasonic Electronic Components	ERJ-3GEYJ132V
S1	Transistor	Infineon Technologies	BCP56
S2	Voltage regulator	Fairchild Semiconductor	LM7805CT
S3	Potentiometer, 2K Ω	Bourns Inc.	3224W-1-202E

table continued next page

Reference Circuit (cont.)

Component ID	Description	Suggested Supplier	P/N
Output			
C201	Chip capacitor, 9.1 pF	ATC	ATC100B9R1BW500XB
C202	Chip capacitor, 300 pF	ATC	ATC100B301JW200XB
C203	Chip capacitor, 10 μ F	TDK Corporation	C5750X7S2A106M230KB
C204	Capacitor, 1 μ F	TDK Corporation	C4532X7R2A105K230KA
C205	Chip capacitor, 300 pF	ATC	ATC100B301JW200XB
L1, L2	Inductor, 8 nH	Coilcraft	A03TGLB
L3	Inductor, 43 nH	Coilcraft	B10TGLB

See next page for package mechanical specifications

Package Outline Specifications

Package H-36265-2

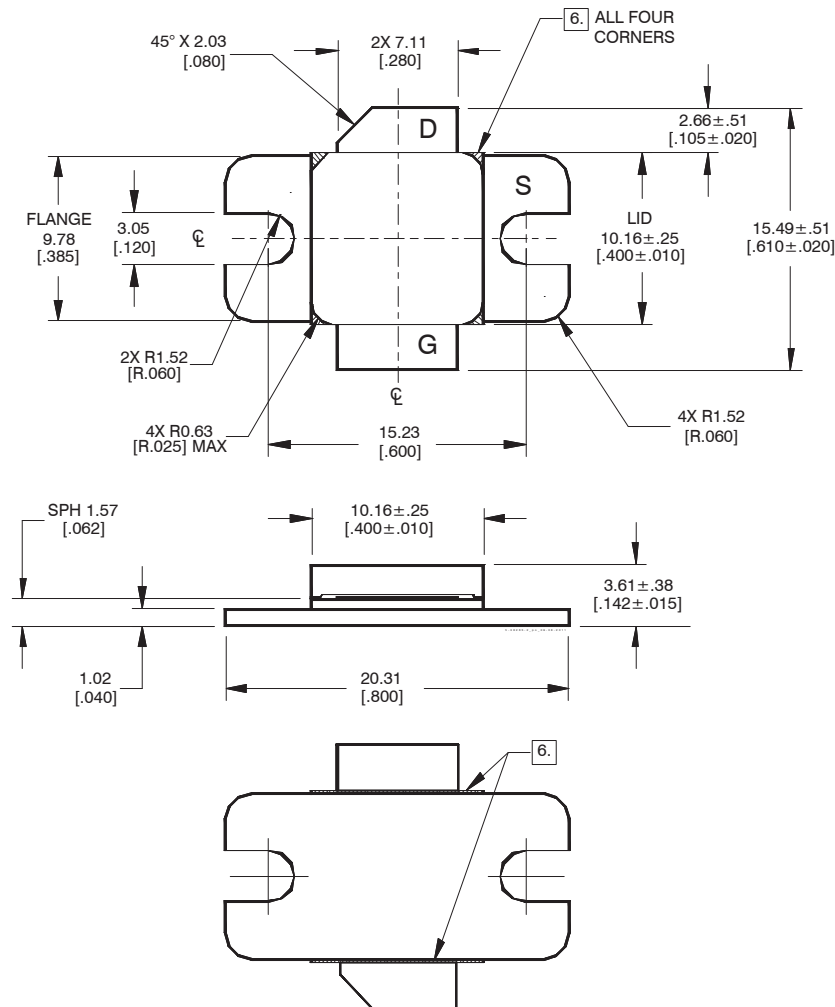


Diagram Notes—unless otherwise specified:

1. Interpret dimensions and tolerances per ASME Y14.5M-1994.
2. Primary dimensions are mm. Alternate dimensions are inches.
3. All tolerances ± 0.127 [.005] unless specified otherwise.
4. Pins: D - drain, G - gate, S - source.
5. Lead thickness: $0.10 + 0.051 / - 0.025$ [.004 + .002 / -.001].
6. Exposed metal plane on top and bottom of ceramic insulator.
7. Gold plating thickness: 1.14 ± 0.38 micron [45 ± 15 microinch].

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Revision History: 2016-04-19

Data Sheet

Previous Version: 2013-07-02, Data Sheet

Page	Subjects (major changes since last revision)
1, 2	Added ESD rating, updated ordering information

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